

Photoelectron Attenuation Lengths

Using

Langmuir-Blodgett Films

Contents

- Introduction
 - Langmuir-Blodgett Films
 - Preparation and uses
 - Attenuation Length
- Cadmium Arachidate Experiment
- Conclusion
- References

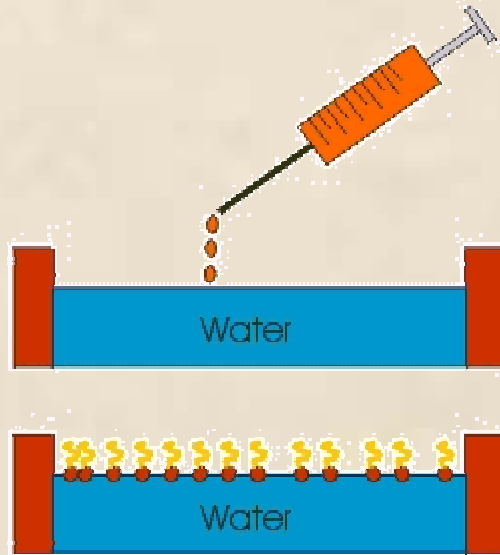
Introduction to Langmuir-Blodgett Films

When an insoluble organic material is introduced to an aqueous surface, it disperses across the surface.

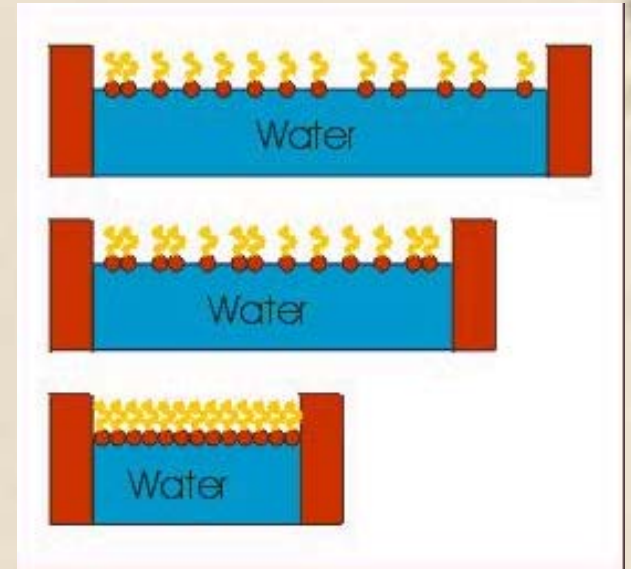


Preparation of LB Films

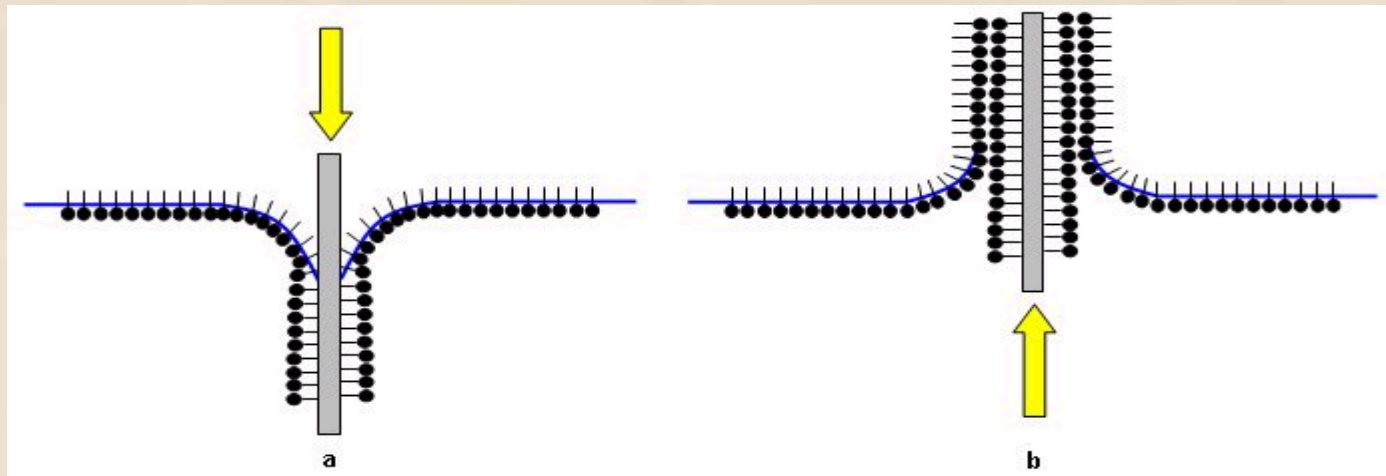
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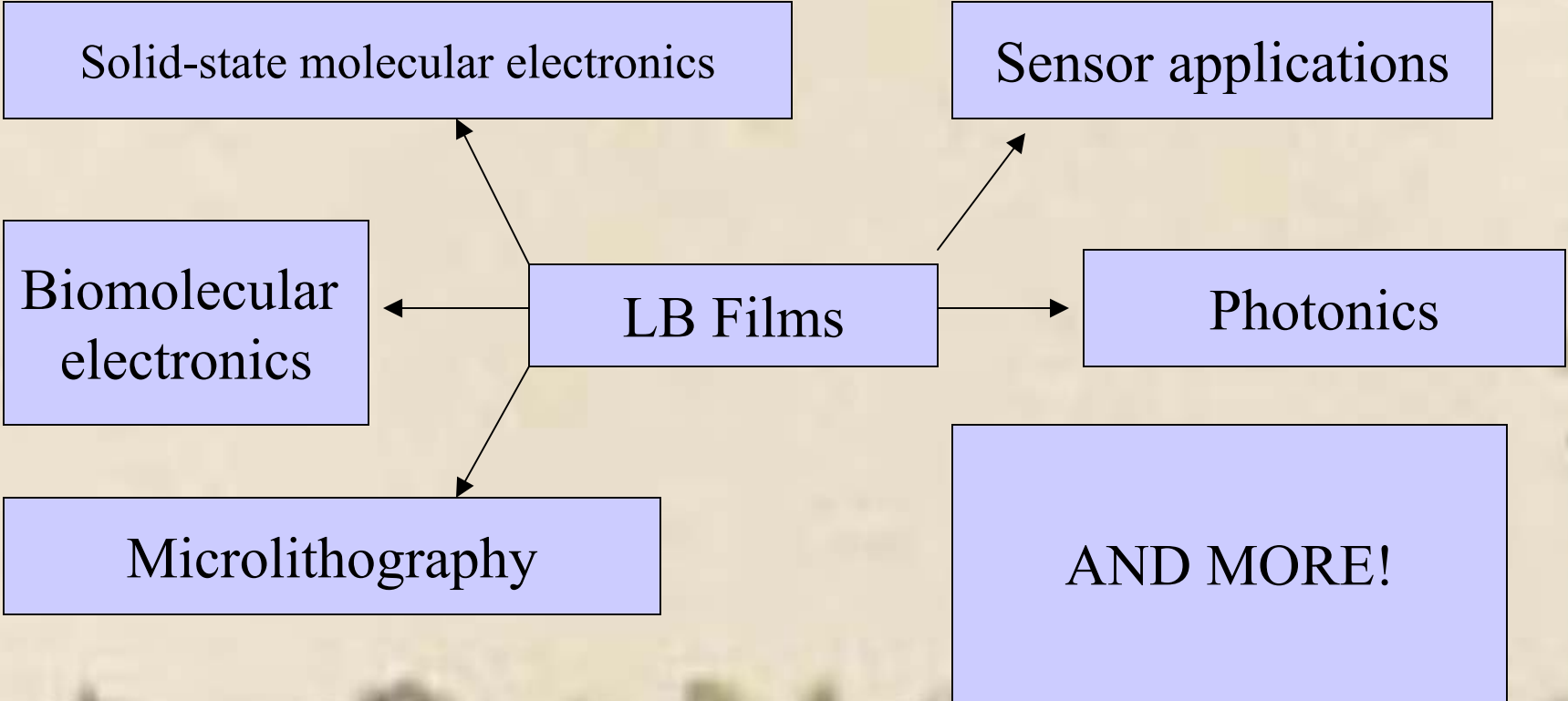
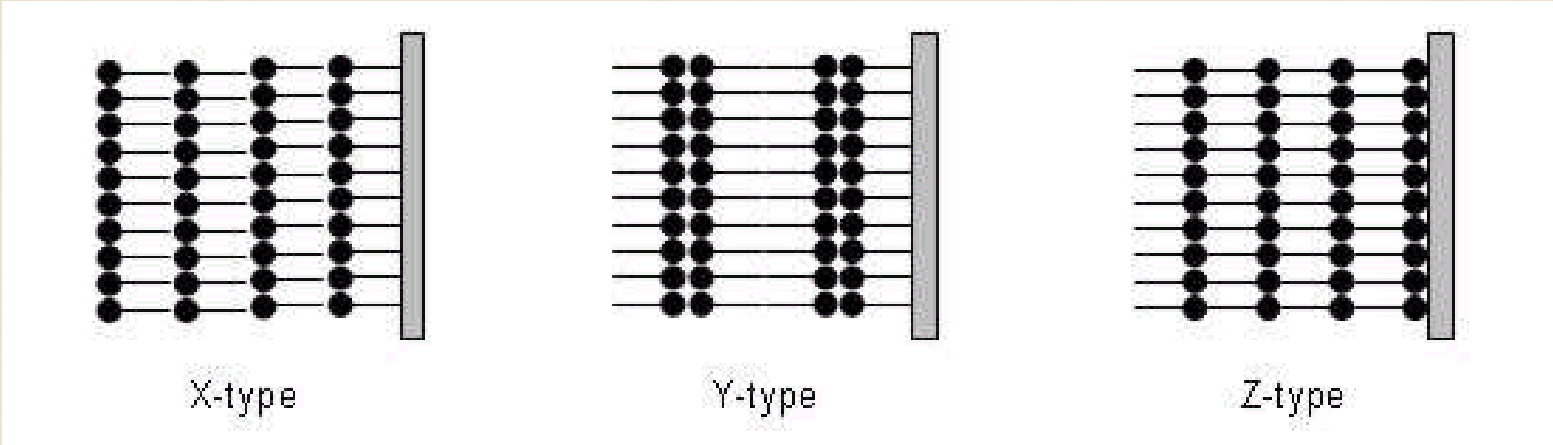


2.



3.



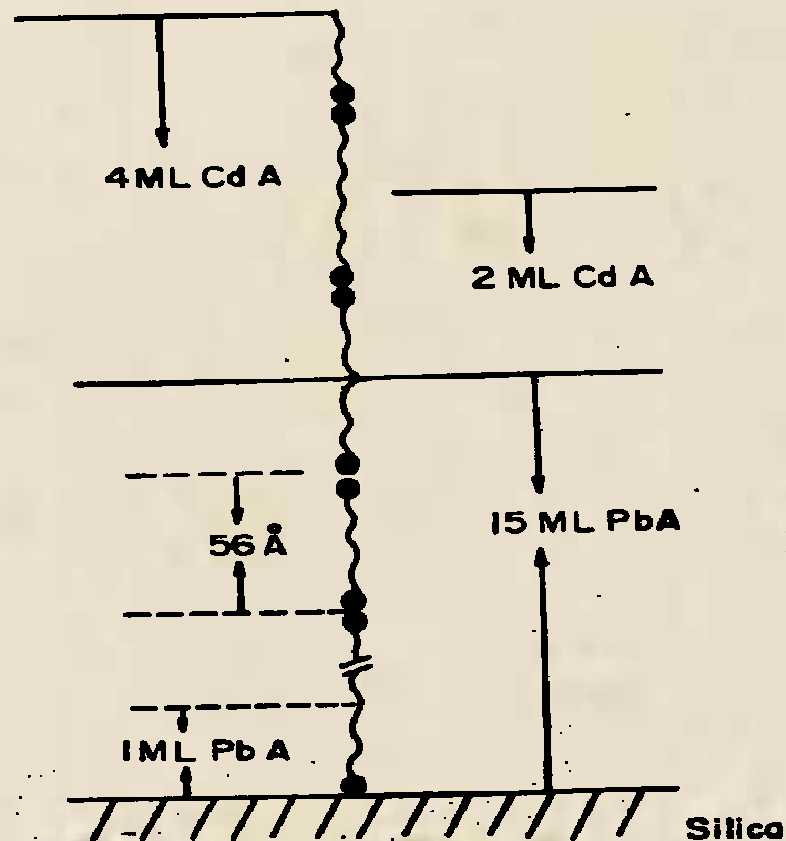


Attenuation Lengths

- * The reduction in level of a quantity as a function of a characteristic parameter.
- * For unconfined radiation from a point source, the attenuation is inversely proportional to the square of the distance from the source.
- * So from the measure of the attenuation lengths is useful in characterisation of the surface
- * For electron in solids, the attenuation lengths can be estimated by variation of x-ray photoelectron intensity with electron take-off angle (ETOA).

Cadmium Arachidate Experiment

- ✓ Films of 2 and 4 monolayers of Cadmium Arachidate (CdA) is deposited on 15 monolayers of PbA.
- ✓ The films are transferred to UHV chamber after drying.



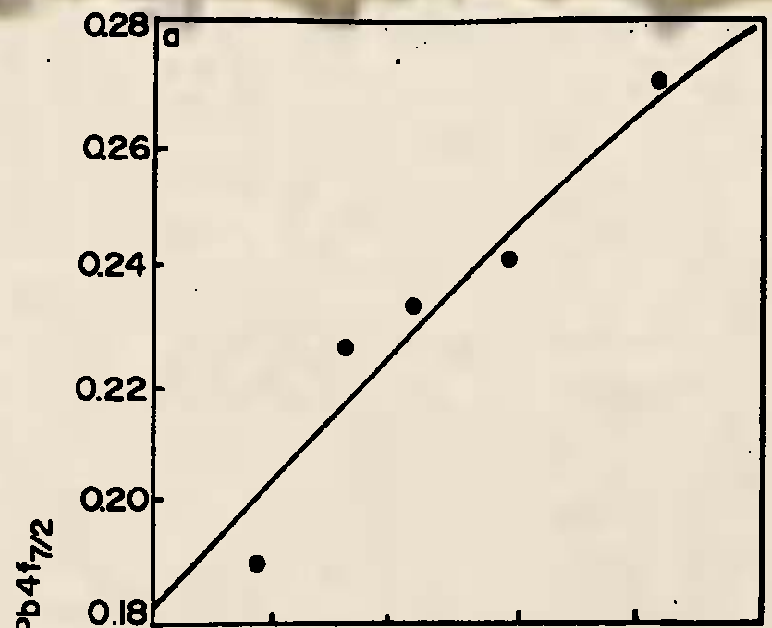
Schematic Diagram of 2 and 4 monolayer CdA LB film on 15 monolayer PbA

The x-ray flux has to be kept at minimum.

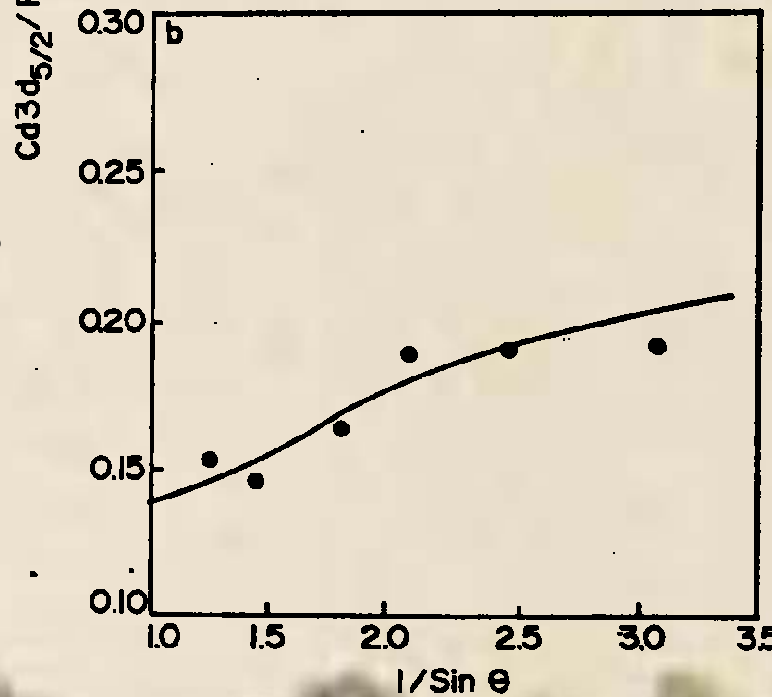
The ETOA varies from 15° to 55° .

The variation of Lead $4f_{7/2}$, Oxygen $1s$ and Cadmium $3d_{5/2}$ is recorded.

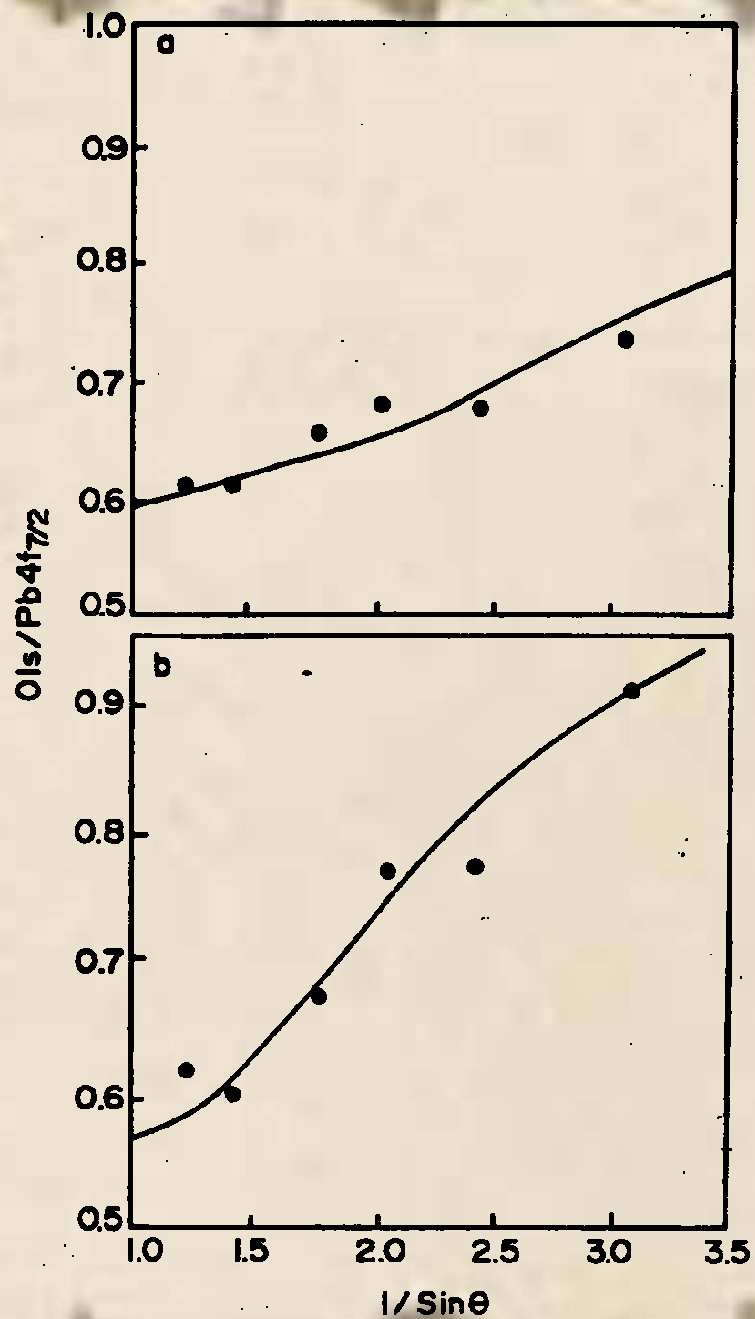
A



B



Cd $3d_{5/2}$ to Pb $4f_{7/2}$ for
(A) 2 ML CdA on PbA
(B) 4 ML CdA on PbA
As a function of $1/\sin\theta$.



O 1s to Pb 4f_{7/2} for
(A) 2 ML CdA on PbA
(B) 4 ML CdA on PbA
As a function of 1/sinθ.

Discrete layer model

The x-ray photoemitted electron flux of energy E attenuated by an overlayer of thickness t having a takeoff angle θ is given by

$$I(E, \theta, t) \propto D(\theta, E) \cdot n_E \cdot \sigma_E \cdot \exp(-t / \lambda \sin \theta)$$

where D is an energy and angle dependent spectrometer response

n_e is the number density of atoms at source

σ_e is the ionization cross section

Λ is the electron attenuation length in the overlayer.

The intensity of the lead signal is given by

$$I_{\text{Pb}} = a[(1 - \gamma) + \gamma \exp(-nt/\lambda \sin \theta)]$$

where n is the number of monolayers of CdA of thickness t each, Λ is the AL of the electrons in CdA and γ is the surface coverage

The signal intensities were expressed as ratios.

$$I_{\text{Cd}}/I_{\text{Pb}} = a \exp(-28/\lambda \sin \theta) / [0.01 + 0.99 \exp(-3t/93 \sin \theta)],$$

$$I_{\text{O}}/I_{\text{Pb}} = a \exp(-28/\lambda \sin \theta) \{ \exp(-16 \times 28/\lambda \sin \theta) + 2 \\ + 2 \exp(-56/\lambda \sin \theta) [1 - \exp(-7 \times 56/\lambda \sin \theta)] / \\ [1 - \exp(-56/\lambda \sin \theta)] \} / [0.01 + 0.99 \exp(-3t/93 \sin \theta)].$$

4 ML CdA/PbA:

$$I_{\text{Cd}}/I_{\text{Pb}} = a [\exp(-84/\lambda \sin \theta) + \exp(-28/\lambda \sin \theta)] / [0.01 + 0.99 \exp(-5t/109 \sin \theta)],$$

$$I_{\text{O}}/I_{\text{Pb}} = a \exp(-28/\lambda \sin \theta) \{ \exp(-18 \times 28/\lambda \sin \theta) + 2 \\ + 2 \exp(-56/\lambda \sin \theta) [1 - \exp(-8 \times 56/\lambda \sin \theta)] / \\ [1 - \exp(-56/\lambda \sin \theta)] \} / [0.01 + 0.99 \exp(-5t/109 \sin \theta)].$$

AL data (in Å) for electrons in CdA in the energy range 950–1350 eV

	Pb $4f_{7/2}$	Cd $3d_{5/2}$	O $1s$
KE (eV)	1350	1081	955
2 ML CdA AL (Å)	93 (118)	42 (81)	45 (75)
4 ML CdA AL (Å)	109	39	48

Conclusion

This method allows for determination of ALs of electrons phototemitted from the overlayer also.

AL for a wide Kinetic Energy Range from measurements of the XPS intensity variation with ETOA in LB films can be done.

References

- Murali Sastry, P. Ganguly, S. Badrinarayanan, A.B. Mandale, S.R.Sainkar, D.V.Paranjape, K.R.Patil and S.K.Chaudary, *J.Chem.Phys.*, **95**, 8631 - 8635 (1991).
- Tamas Marek, Csaba Szeles, Karoly Suvegh, Eva Kiss, Attila Vertes and Kelvin G. Lynn, *Langmuir*, **15**, 8189 - 8196 (1999)